HiPerFRED

### **DSEP29-06**A

$V_{\text{RRM}}$	=	600 V
I <sub>FAV</sub>	=	30 A
t <sub>rr</sub>	=	35 ns

High Performance Fast Recovery Diode Low Loss and Soft Recovery Single Diode

### Part number

**DSEP29-06A** 



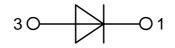
Package: TO-220

RoHS compliant

• Industry standard outline

• Epoxy meets UL 94V-0

Backside: cathode



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch

### **Applications:**

- Antiparallel diode for high frequency
- switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode Rectifiers in switch mode power
- supplies (SMPS)
- Uninterruptible power supplies (UPS)

#### Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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# LIXYS

## **DSEP29-06A**

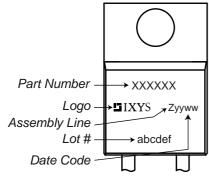
Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			600	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			600	V
I <sub>R</sub>	reverse current, drain current	$V_{R} = 600 V$	$T_{VJ} = 25^{\circ}C$			250	μA
		$V_{R} = 600 V$	$T_{vJ} = 150^{\circ}C$			1	mA
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 30 A	$T_{VJ} = 25^{\circ}C$			1.61	V
		$I_{F} = 60 \text{ A}$				1.94	V
		$I_{\rm F} = 30  {\rm A}$	T <sub>vJ</sub> = 150°C			1.26	V
		$I_{F} = 60 \text{ A}$				1.56	V
I FAV	average forward current	T <sub>c</sub> =135°C	T <sub>vJ</sub> = 175°C			30	А
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage		$T_{vJ} = 175^{\circ}C$			0.91	V
r <sub>F</sub>	slope resistance } for power in	oss calculation only				9.4	mΩ
$R_{thJC}$	thermal resistance junction to cas	e				0.9	K/W
R <sub>thCH</sub>	thermal resistance case to heatsir	nk			0.50		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			165	W
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			250	А
C	junction capacitance	$V_{R}$ = 400 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		26		pF
I <sub>RM</sub>	max. reverse recovery current		$T_{VJ} = 25 °C$		6		Α
		$I_{\rm F} = 30  \text{A};  V_{\rm R} = 300  \text{V}$	$T_{vJ} = 100 ^{\circ}C$		10		А
t <sub>rr</sub>	reverse recovery time	$I_{F} = 30 \text{ A}; V_{R} = 300 \text{ V}$ $-di_{F} / dt = 200 \text{ A} / \mu \text{s}$	$T_{VJ} = 25 ^{\circ}C$		35		ns
		)	$T_{vJ} = 100 ^{\circ}C$		100		ns



## **DSEP29-06A**

Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal			35	Α
T <sub>vj</sub>	virtual junction temperature		-55		175	°C
T <sub>op</sub>	operation temperature		-55		150	°C
T <sub>stg</sub>	storage temperature		-55		150	°C
Weight				2		g
M <sub>D</sub>	mounting torque		0.4		0.6	Nm
F <sub>c</sub>	mounting force with clip		20		60	Ν





Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEP29-06A	DSEP29-06A	Tube	50	474819

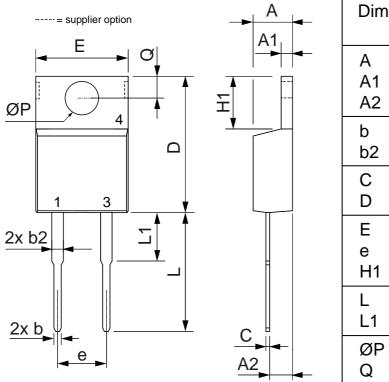
Similar Part	Package	Voltage class
DSEP29-06AS	TO-263AB (D2Pak) (2)	600
DSEP30-06A	TO-247AD (2)	600
DSEP30-06B	TO-247AD (2)	600
DSEP30-06BR	ISOPLUS247 (2)	600
DHG30I600PA	TO-220AC (2)	600
DHG30I600HA	TO-247AD (2)	600
DHG30IM600PC	TO-263AB (D2Pak) (2)	600

Equivalent Circuits for Simulation		* on die level	T <sub>vJ</sub> = 175 °C	
	- Ro-	Fast Diode		
V <sub>0 max</sub>	threshold voltage	0.91		V
$R_{0 max}$	slope resistance *	6.1		mΩ

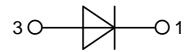
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### Outlines TO-220



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
С	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	5.08	BSC	0.200	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



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